Unit in mm

TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

# **TLP112**

**Digital Logic Isolation** 

Line Receiver

Switching Power Supply Feedback Control

**Transistor Inverter** 

The TOSHIBA mini flat coupler TLP112 is a small outline coupler, suitable for surface mount assembly.

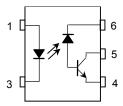
TLP112 consists of a GaA $\ell$ As light emitting diode, optically coupled to a high speed detector of one chip photodiode-transistor.

- Isolation voltage: 2500 Vrms (min.)
- Switching speed:  $t_{pHL} = 0.8\mu s$ ,  $t_{pLH} = 2 \mu s(max.)$  $(R_L = 4.1 \text{ k}\Omega)$
- TTL compatible
- UL recognized: UL1577, file no. E67349

# $7.0 \pm 0.4$ 11-4C2 **TOSHIBA** 11-4C2

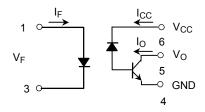
Weight: 0.09g

#### Pin Configuration (top view)



- 1: ANODE
- 3 : CATHODE 4 : EMITTER (GND)
- 5: COLLECTOR (OUTPUT)
- 6 : V<sub>CC</sub>

#### **Schematic**





#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	(Note 1)	l <sub>F</sub>	25	mA
	Pulse forward current	(Note 2)	I <sub>FP</sub>	50	mA
LED	Peak transient forward current	(Note 3)	I <sub>FPT</sub>	1	А
	Reverse voltage		V <sub>R</sub>	5	٧
	Diode power dissipation	(Note 4)	PD	45	mW
	Output current		IO	8	mA
ō	Peak output current		l <sub>OP</sub>	16	mA
Detector	Supply voltage		V <sub>CC</sub>	-0.5~15	V
۵	Output voltage		Vo	-0.5~15	V
	Output power dissipation	(Note 5)	Po	100	mW
Оре	Operating temperature range		T <sub>opr</sub>	-55~100	°C
Stor	Storage temperature range		T <sub>stg</sub>	-55~125	°C
Lea	Lead soldering temperature(10s)		T <sub>sol</sub>	260	°C
Isolation voltage (AC, 1 min., R.H ≤ 60%, Note 6		Note 6)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Derate 0.8 mA / °C above 70°C.

(Note 2) 50% duty cycle,1ms pulse width. Derate 1.6mA / °C above 70°C.

(Note 3) Pulse width  $\leq 1 \mu s$ , 300pps.

(Note 4) Derate 0.9mW / °C above 70°C.

(Note 5) Derate 2mW / °C above 70°C.



# **Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit	
LED	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 16mA	_	1.65	1.85	V	
	Forward voltage temperature coefficient	ΔV <sub>F</sub> / ΔTa	I <sub>F</sub> = 16mA	_	-2	1	mV / °C	
	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5V	_	_	10	μΑ	
	Capacitance between terminals	СТ	V <sub>F</sub> = 0, f = 1MHz	1	45	_	pF	
Detector	High level output current	I <sub>OH (1)</sub>	$I_F = 0mA, V_{CC} = V_O = 5.5V$	_	3	500	nA	
		I <sub>OH (2)</sub>	I <sub>F</sub> = 0mA, V <sub>CC</sub> = V <sub>O</sub> = 15V	_	_	5	μА	
		Іон	I <sub>F</sub> = 0mA, V <sub>CC</sub> = V <sub>O</sub> = 15V Ta = 70°C	_	_	50		
	High level supply current	Іссн	I <sub>F</sub> = 0mA, V <sub>CC</sub> = 15V	_	0.01	1	μΑ	
	Current transfer ratio	I <sub>O</sub> / I <sub>F</sub>	I <sub>F</sub> =16mA, V <sub>CC</sub> = 4.5V V <sub>O</sub> = 0.4V	10	_	_	%	
Coupled	Low level output voltage	V <sub>OL</sub>	I <sub>F</sub> = 16 mA, V <sub>CC</sub> = 4.5V I <sub>O</sub> = 1.1mA	_	_	0.4	V	
	Isolation resistance	R <sub>S</sub>	R.H. ≤ 60% V <sub>S</sub> = 500V DC (Note 6)	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω	
	Stray capacitance between input to output	CS	V <sub>S</sub> = 0, f = 1MHz (Note 6)	_	0.8		pF	

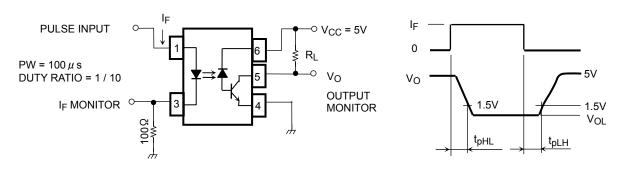
# **Switching Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time (H→L)	t <sub>pHL</sub>	1	$I_F = 0 \rightarrow 16$ mA V <sub>CC</sub> = 5V, R <sub>L</sub> = 4.1kΩ	_	_	0.8	μs
Propagation delay time (L→H)	t <sub>pLH</sub>	1	$I_F$ = 16 $\rightarrow$ 0mA V <sub>CC</sub> = 5V, R <sub>L</sub> = 4.1kΩ	-	_	2.0	μs
Common mode transient immunity at high output level	CM <sub>H</sub>	2	$I_F = 0mA, V_{CM} = 200V_{p-p}$ R <sub>L</sub> = 4.1k $\Omega$	_	1500	_	V / µs
Common mode transient immunity at low output level	CML	2	$I_F = 16\text{mA}, V_{CM} = 200V_{p-p}$ R <sub>L</sub> = 4.1k $\Omega$		-1500		V / µs

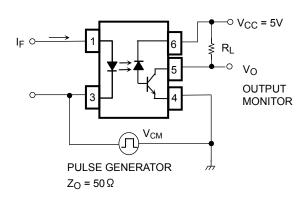
(Note 6) Device considered a two–terminal device: Pins 1 and 3 shorted together and Pin 4, 5 and 6 shorted together.

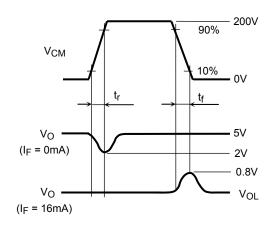
(Note 7) Maximum electrostatic discharge voltage for any pins: 100V (C=200pF, R=0)

# **Test Circuit 1: Switching Time Test Circuit**

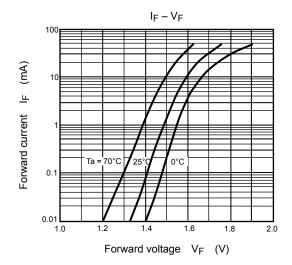


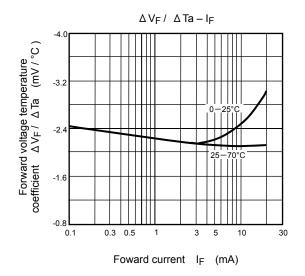
### **Test Circuit 2: Common Mode Transient Immunity Test Circuit**

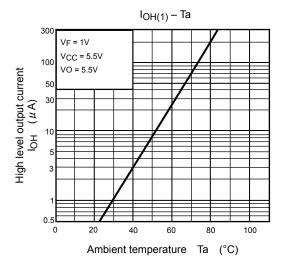


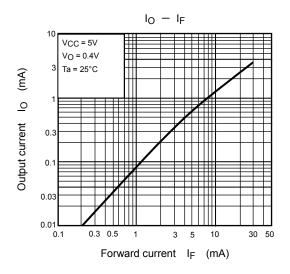


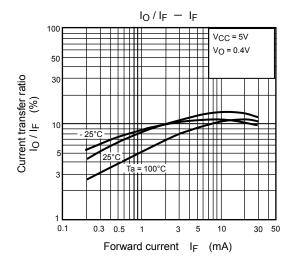
$${\sf CM}_H = \frac{160({\sf V})}{t_{\sf f}(\mu {\sf s})}, {\sf CM}_L = \frac{160({\sf V})}{t_{\sf f}(\mu {\sf s})}$$

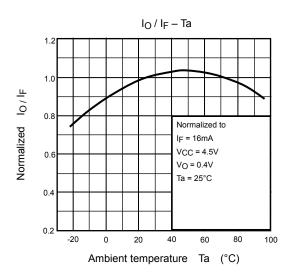




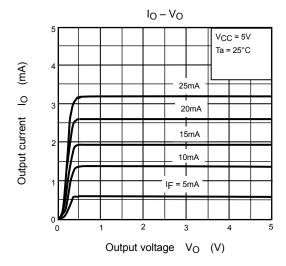


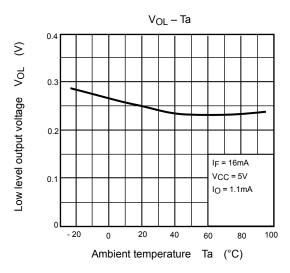


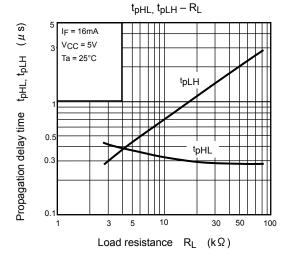


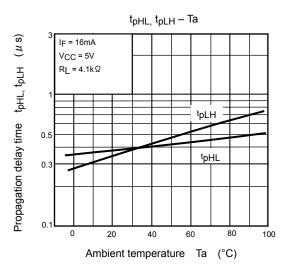


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